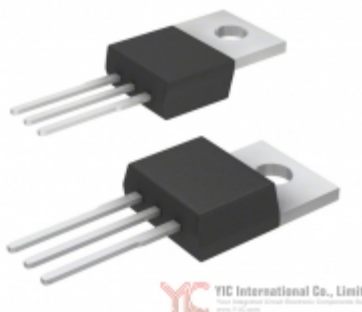



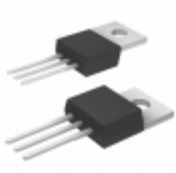


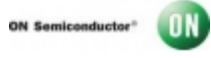


	<p><b>NTP5863NG</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTP5863NG</a></p>
	<p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p>
	<p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 97A TO-220AB</p>
<p>Image may be representation. See specs for product details.</p>	<p><b>Datenblätter:</b>  <a href="#">NTP5863NG.pdf</a></p>
	<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>
	<p><b>Lagerzustand:</b> New original, 37464 pcs Stock Available.</p>
	<p><b>Liefern von:</b> Hong Kong</p>
	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	<a href="#">NTP5863NG</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 97A TO-220AB
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	37464 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	150W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	97A (Tc)
Rds On (Max) @ Id, Vgs	7.8 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	55nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3200pF @ 25V
Verpackung	Tube



















































NTP5863NG ist neu im Original, Suche NTP5863NG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP5863NG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP5863NG: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTP5863N</b> VB NTP5863N VB</p>	 <p><b>NTP5860NL</b> O NTP5860NL O</p>	 <p><b>NTP5864NG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 63A TO-220</p>	 <p><b>NTP5860NG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 220A TO-220-3</p>
 <p><b>NTP60N06</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>	 <p><b>NTP5864N</b> AMI Semiconductor / ON Semiconductor NTP5864N ON</p>	 <p><b>NTP60N06G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>	 <p><b>NTP60N06L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>

heiße Teile

Mehr

 NTP30N06LG	 NTP30N20	 NTP30N20G	 NTP35N15	 NTP35N15G
 NTP4302G	 NTP45N06	 NTP45N06G	 NTP45N06L	 NTP45N06LG
 NTP477M04TDR	 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG
 NTP5411NG	 NTP5412NG	 NTP5426N	 NTP5426NG	 NTP5860N
 NTP5860NG	 NTP5860NL	 NTP5860NLG	 NTP5862NG	 NTP5863N
 NTP5864N	 NTP5864NG	 NTP60N06	 NTP60N06G	 NTP60N06L
 NTP60N06LG	 NTP6410AN	 NTP6410ANG	 NTP6411AN	 NTP6411ANG
 NTP6412AN	 NTP6412ANG	 NTP6413AN	 NTP6413ANG	 NTP6448ANG
 NTP65N02R	 NTP65N02RG	 NTP75N03-006	 NTP75N03-06	 NTP75N03-06G
 NTP75N03-6G	 NTP75N03L09	 NTP75N03L09G	 NTP75N03R	 NTP75N03RG

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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